

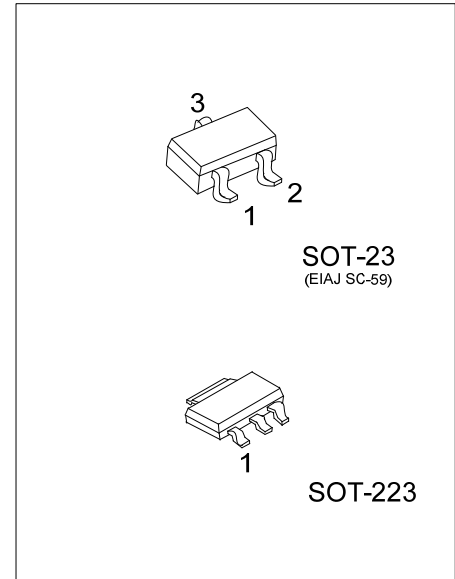
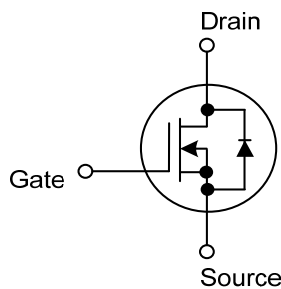
**UF601****Power MOSFET****0.185A, 600V N-CHANNEL
DEPLETION-MODE POWER
MOSFET****DESCRIPTION**

The UTC **UF601** is an N-channel power MOSFET using UTC's advanced technology to provide the customers with high switching speed.

FEATURES

* $R_{DS(ON)} \leq 120 \Omega$ @ $V_{GS}=0V$, $I_D=3.0mA$

* High Switching Speed

SYMBOL**ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UF601L-AA3-R	UF601G-AA3-R	SOT-223	G	D	S	Tape Reel
UF601L-AE3-R	UF601G-AE3-R	SOT-23	G	S	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

UF601G-AA3-R (1) Packing Type (2) Package Type (3) Green Package	(1) R: Tape Reel (2) AA3: SOT-223, AE3: SOT-23 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING

SOT-223	SOT-23
F601 L: Lead Free G: Halogen Free Date Code	F601 L: Lead Free G: Halogen Free

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage (Note 2)		V _{DSS}	600	V
Drain-Gate Voltage (Note 2)		V _{DGX}	600	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current	Continuous	I _D	0.185	A
	Pulsed	I _{DM}	0.740	A
Power Dissipation	SOT-223	P _D	0.8	W
	SOT-23		0.5	W
Junction Temperature		T _J	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. T_J=+25°C~+150°C

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223	θ _{JA}	150	°C/W
	SOT-23		250	°C/W

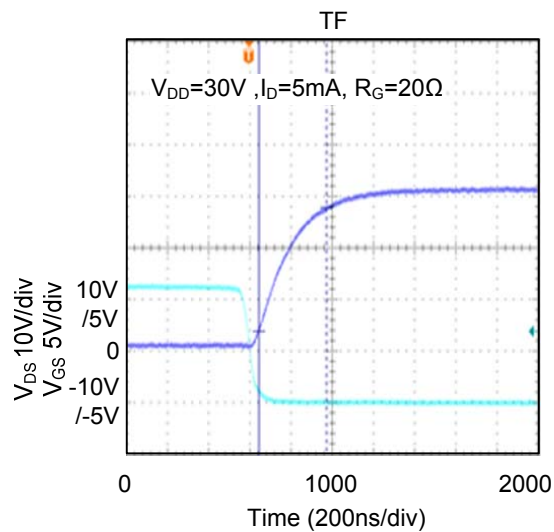
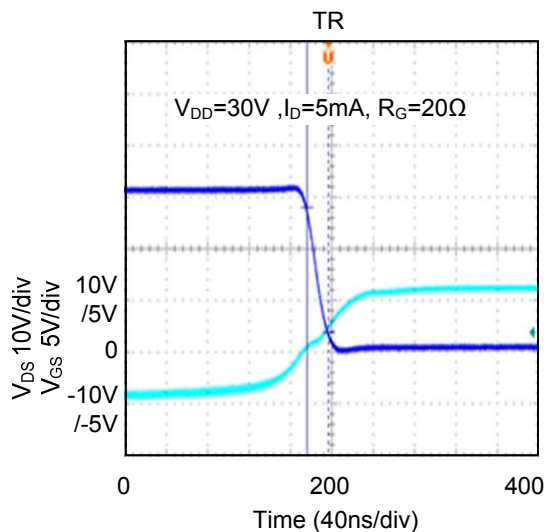
■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =250μA, V _{GS} =-5V	600			V
Drain-Source Leakage Current		I _{D(OFF)}	V _{DS} =600V, V _{GS} =-5V			0.1	μA
Gate-Source Leakage Current	Forward	I _{GSS}	V _{GS} =+20V, V _{DS} =0V			+100	nA
	Reverse		V _{GS} =-20V, V _{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate to Source Cut Off Voltage		V _{GS(OFF)}	V _{DS} =3V, I _D =8μA	-1.0		-3.0	V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =25V, V _{GS} =0V	7.0			mA
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =0V, I _D =3.0mA		60	120	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		53		pF
Output Capacitance		C _{OSS}			3000		pF
Reverse Transfer Capacitance		C _{RSS}			2.6		pF
SWITCHING PARAMETERS							
Total Gate Charge		Q _G	V _{GS} =-5~5V, V _{DS} =30V, I _D =5mA		7.6		nC
Gate to Source Charge		Q _{GS}			4		nC
Gate to Drain Charge		Q _{GD}			0.4		nC
Turn-ON Delay Time		t _{D(ON)}	V _{GS} =-5~5V, V _{DD} =30V, I _D =5mA, R _G =20Ω		42		ns
Rise Time		t _R			20		ns
Turn-OFF Delay Time		t _{D(OFF)}			80		ns
Fall-Time		t _F			300		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Drain-Source Diode Forward Voltage		V _{SD}	I _{SD} =3.0mA, V _{GS} =-10V			1.4	V

Note: 1. Repetitive rating, pulse width limited by maximum junction temperature

2. Pulse width≤380μs; duty cycle≤2%

■ TYPICAL CHARACTERISTICS



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